

Instrumentation Operational Amplifier

GENERAL DESCRIPTION

The μPC254 of Monolithic Instrumentation Operational Amplifier exhibits excellent performance in low signal level applications with the flexibility and ease of application of a fully protected, internally compensated op amp. Main features are low offset voltage, bias current and noise and high gain, input impedance, CMRR and SVRR.

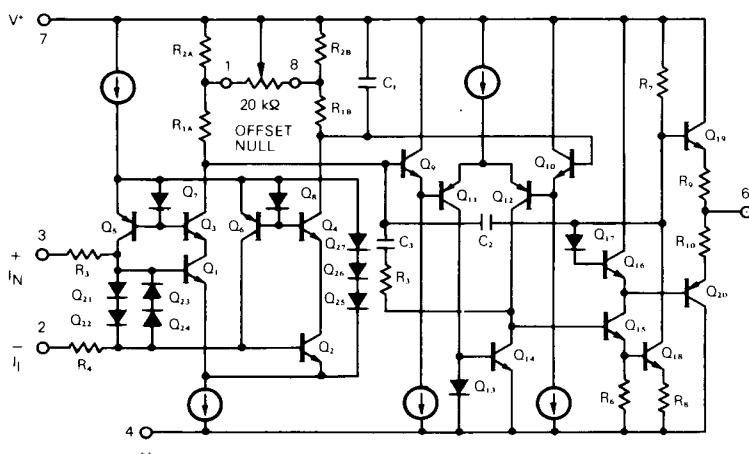
The μPC254 is an optimum choice for a wide variety of applications including strain gauge, thermocouple bridges, high gain active filters, buffers, integrators, and sample and hold amplifiers.

EQUIVALENT CIRCUIT

FEATURES

- Low Input Offset Voltage Drift vs Temp $0.4 \mu\text{V}/^\circ\text{C}$ (Null) Typ.
- Low Input Offset Voltage Drift vs Time $0.4 \mu\text{V}/\text{Month}$ Typ.
- Low Input Offset Voltage 0.3 mV Typ.
- Low Input Bias Current $\pm 1.8 \text{nA}$ Typ.
- High Gain
- Low Noise
- High CMRR
- Internally Frequency Compensated.
- Easy Offset Nulling
- OP-05C Direct Replacement

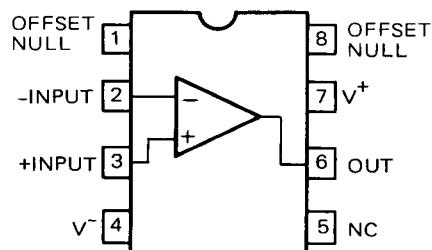
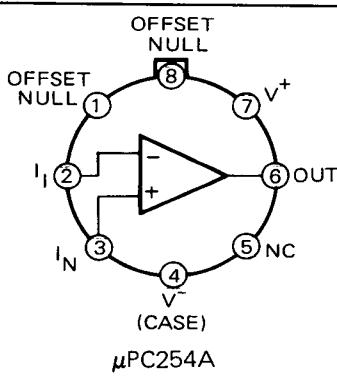
ORDERING INFORMATION

**μPC254A**

8 pin Metal Can Package

**μPC254D**8 pin Ceramic DIP
(Dual In-Line Package)

CONNECTION DIAGRAM (Top View)

**μPC254D**

ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ C$)

PARAMETER		μPC254	UNIT
Voltage between V^+ and V^-		44	V
Power Dissipation*	A or D Package	500	mW
Differential Input Voltage		±30	V
Input Voltage (Note 1)		±22	V
Output Short Circuit Duration		Indefinite	s
Operating Temperature Range	A or D Package	-20 to +80	°C
Storage Temperature Range	A Package	-60 to +175	°C
	D Package	-55 to +150	

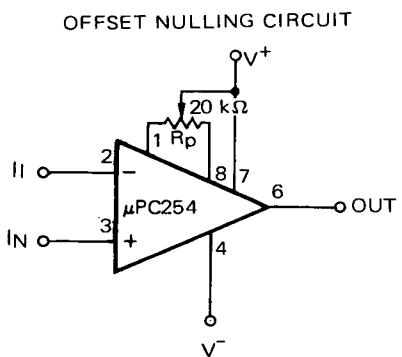
Note 1: For supply voltages less than ±22 V, the absolute maximum input voltage is equal to the supply voltage.

* See thermal information in chapter 11.

ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ C$, $V^\pm = \pm 15 V$)

CHARACTERISTIC	MIN.	TYP.	MAX.	UNIT	CONDITIONS
Input Offset Voltage		0.3	1.3	mV	$R_s \leq 100 \Omega$
Average Input Offset Voltage Drift		1.2	4.5	$\mu V/^\circ C$	$R_s \leq 100 \Omega$, unnull (Note 2)
Average Input Offset Voltage Drift		0.4	1.5		$R_s \leq 100 \Omega$, null, $R_p=20 k\Omega$ (Note 2)
Input Offset Current		1.8	6.0	nA	
Average Input Offset Current Drift		12	50	$pA/^\circ C$	(Note 2)
Input Bias Current		±1.8	±7.0	nA	
Average Input Bias Current Drift		18	50	$pA/^\circ C$	(Note 2)
Input Resistance – Diff Mode	8	33		MΩ	
Large Signal Voltage Gain	120	500		V/mV	$R_L \geq 2 k\Omega$, $V_o = \pm 10 V$
Supply Current		3.2	5.0	mA	
		0.67	1.3		$V^\pm = \pm 3 V$
Power Consumption		95	150	mW	
Maximum Output Voltage Swing	±12.0	±13.0		V	$R_L \geq 10 k\Omega$
	±11.5	±12.8			$R_L \geq 2 k\Omega$
	±1.45	±1.6			$V^\pm = \pm 3 V$, $R_L \geq 2 k\Omega$
Common Mode Rejection Ratio	100	120		dB	
Power Supply Rejection Ratio	90	104		dB	$V^\pm = \pm 3 V \rightarrow \pm 18 V$
Offset Adjustment Range		4		mV	$R_p = 20 k\Omega$
Input Noise Voltage		0.5		μV_{p-p}	$R_s = 10 k\Omega$, $f = 0.1 \sim 10 Hz$ (Note 2)
Input Noise Voltage Density		10.5	20.0	nV/\sqrt{Hz}	$f_o = 10 Hz$ (Note 2)
		10.2	13.5		$f_o = 100 Hz$ (Note 2)
		9.8	11.5		$f_o = 1000 Hz$ (Note 2)
Input Noise Current Density		0.35	0.90	pA/\sqrt{Hz}	$f_o = 10 Hz$ (Note 2)
		0.15	0.27		$f_o = 100 Hz$ (Note 2)
		0.13	0.18		$f_o = 1000 Hz$ (Note 2)
Long Term Input Offset Voltage Stability		0.4	2.0	$\mu V/Mo$	(Note 2)

Note 2: Parameter is not 100 % tested, 90 % of units meet this specification.



The μ PC254 is designed to provide lowest drift performance when trimmed with a $20\text{ k}\Omega$ potentiometer. When fine resolution of trimming is desired or where unwanted changes in potentiometer position with time and temperature could create unacceptable offsets, the sensitivity to offset vs potentiometer may be reduced by using the circuit shown below.

